<u>TOSHIBA</u>

TOSHIBA Photocoupler GaAs Ired & Photo-Transistor

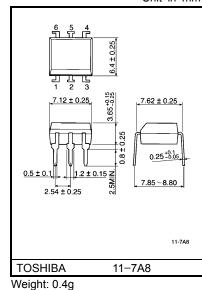
TLP371, TLP372

Office Machine Household Use Equipment Telecommunication Solid State Relay Programmable Controllers

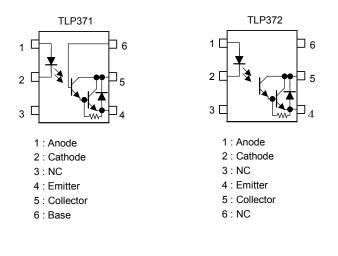
The TOSHIBA TLP371 and TLP372 consists of a gallium arsenide infrared emitting diode optically coupled to a darlington connected photo-transistor which has an integrated base-emitter resistor to optimize switching speed and elevated temperature characteristics in a six lead plastic DIP package.

TLP372 is no-base internal connection for high–EMI environments.

- Current transfer ratio: 1000% (min) (IF = 1mA)
- Isolation voltage: 5000 Vrms (min)
- UL recognized: UL1577, file no. E67349



Pin Configurations (top view)



Unit in mm

Absolute Maximum Ratings (Ta = 25°C)

	Characteristic	Symbol	Rating	Unit
	Forward current	lF	60	mA
LED	Forward current derating (Ta ≥ 39°C)	ΔI _F / °C	-0.7	mA / °C
	Peak forward current (100µs pulse, 100pps)	IFP	1	А
_	Reverse voltage	V _R	5	V
	Junction temperature	Tj	125	°C
	Collector-emitter voltage	V _{CEO}	300	V
	Collector-base voltage (TLP371)	V _{CBO}	300	V
	Emitter-collector voltage	V _{ECO}	0.3	V
Detector	Emitter-base voltage (TLP371)	V _{EBO}	7	V
	Collector current	Ιc	150	mA
	Power dissipation	P _C	300	mW
	Power dissipation derating (Ta ≥ 25°C)	ΔP _C / °C	-3.0	mW / °C
	Junction temperature	Тј	125	°C
Stor	age temperature range	T _{stg}	-55~125	°C
Operating temperature range		T _{opr}	-55~100	°C
Lead soldering temperature (10 s)		T _{sold}	260	°C
Total package power dissipation		PT	350	mW
Total package power dissipation derating (Ta \geq 25°C)		ΔP _T / °C	-3.5	mW / °C
Isola	ation voltage (AC, 1min., R.H. ≤ 60%) (Note 1)	BVS	5000	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Device considered a two terminal device: Pins 1, 2 and 3 shorted together and pins 4,5 and 6 shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min	Тур.	Max	Unit
Supply voltage	V _{CC}	_	_	200	V
Forward current	IF		16	25	mA
Collector current	Ι _C	-	-	120	mA
Operating temperature	T _{opr}	-25	_	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Individual Electrical Characteristics (Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	V _F	I _F = 10 mA	1.0	1.15	1.3	V
LED	Reverse current	I _R	V _R = 5 V	_	_	10	μA
	Capacitance	CT	V = 0, f = 1 MHz	_	30	_	pF
	Collector–emitter breakdown voltage	V _(BR) CEO	I _C = 0.1 mA	300	_	_	V
	Emitter–collector breakdown voltage	V _{(BR) ECO}	I _E = 0.1 mA	0.3	-	-	V
	Collector–base breakdown voltage (TLP371)	V _(BR) CBO	I _C = 0.1 mA	300	-	-	V
	Emitter–base breakdown voltage (TLP371)	V _{(BR) EBO}	I _E = 0.1 mA	7	-	-	V
Detector		I _{CEO}	V _{CE} = 200 V	_	10	200	nA
Dete	Collector dark current		V _{CE} = 200 V Ta = 85 °C	_	_	20	μA
	Collector dark current (TLP371)	ICER	V _{CE} = 200 V Ta = 85 °C, R _{BE} = 10 MΩ	_	0.5	10	μA
	Collector dark current (TLP371)	I _{CBO}	V _{CE} = 200 V	—	0.1	_	nA
	DC forward current gain (TLP371)	h _{FE}	V _{CE} = 5 V, I _C = 10 mA	_	7000	_	_
	Capacitance (collecter to emitter)	C _{CE}	V = 0, f = 1 MHz	_	10	—	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Mln	Тур.	Max	Unit
Current transfer ratio	I _C / I _F	I _F = 1 mA, V _{CE} = 1 V	1000	4000	_	%
Saturated CTR	I _C / I _{F (sat)}	I _F = 10 mA, V _{CE} = 1 V	500	_	—	%
Base photo-current (TLP371)	I _{PB}	I _F = 1 mA, V _{CB} = 1 V	_	6	_	μA
Collector–emitter saturation voltage	V _{CE (sat)}	I _C = 10 mA, I _F = 1 mA	_	_	1.0	v
		I _C = 100 mA, I _F = 10 mA	0.3	_	1.2	v

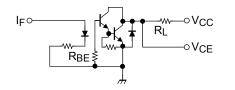
Isolation Characteristics (Ta = 25°C)

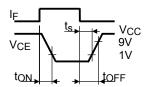
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance (input to output)	CS	V _S = 0, f = 1 MHz	_	0.8	_	pF
Isolation resistance	R _S	V _S = 500 V	5×10 ¹⁰	10 ¹⁴		Ω
		AC, 1 minute	5000	_	_	V
Isolation voltage	BVS	AC, 1 second, in oil	_	10000	_	V _{rms}
		DC, 1 minute, in oil	_	10000	_	V _{dc}

Switching Characteristics (Ta = 25°C)

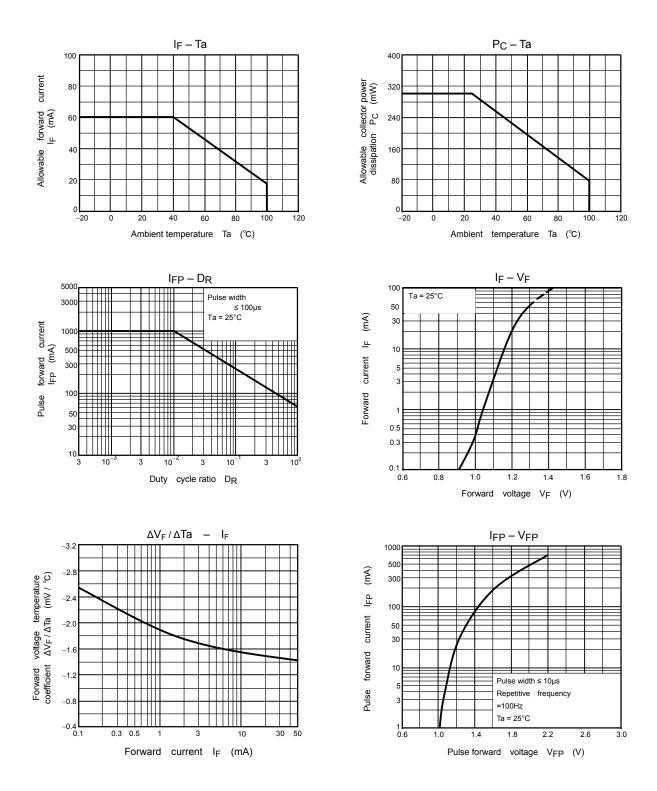
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Rise time	tr		_	40	_	
Fall time	t _f	V _{CC} = 10 V I _C = 10 mA	_	15	—	116
Turn–on time	t _{on}	$R_L = 100\Omega$	_	50	_	μs
Turn–off time	t _{off}		_	15	—	
Turn–on time	t _{ON}	R _L = 180Ω (Fig.1)	_	3	_	
Storage time	ts	R _{BE} = OPEN	—	45	—	μs
Turn-off time	tOFF	V _{CC} = 5 V, I _F = 16 mA	_	90	_	
Turn–on time	t _{ON}	R _L = 180Ω (Fig.1)	_	5	—	
Storage time	ts	R _{BE} = 10 MΩ(TLP371)	_	40	_	μs
Turn-off time	toff	V _{CC} = 10 V, I _F = 16 mA	_	80	—	

Fig.1: Switching time test circuit

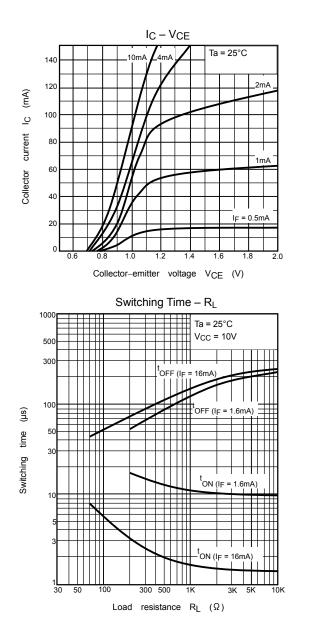


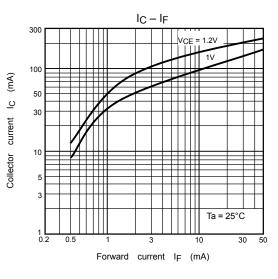


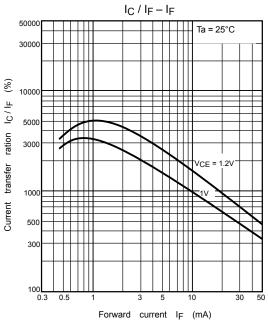
TOSHIBA



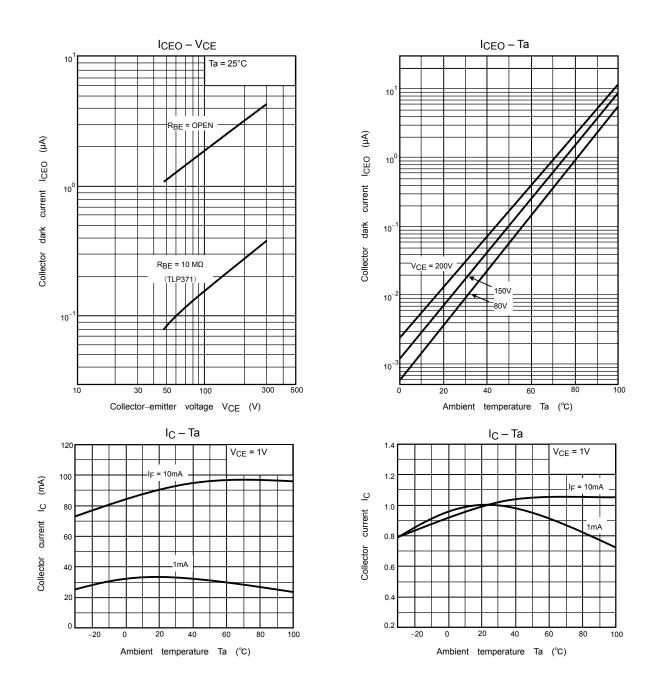
TOSHIBA







TOSHIBA



7

RESTRICTIONS ON PRODUCT USE

20070701-EN

- The information contained herein is subject to change without notice.
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
 In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc.
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in his document shall be made at the customer's own risk.
- The products described in this document shall not be used or embedded to any downstream products of which manufacture, use and/or sale are prohibited under any applicable laws and regulations.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any patents or other rights of TOSHIBA or the third parties.
- GaAs(Gallium Arsenide) is used in this product. The dust or vapor is harmful to the human body. Do not break, cut, crush or dissolve chemically.
- Please contact your sales representative for product-by-product details in this document regarding RoHS compatibility. Please use these products in this document in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances. Toshiba assumes no liability for damage or losses occurring as a result of noncompliance with applicable laws and regulations.